

LM329 Precision Reference

Check for Samples: LM329

FEATURES

- 0.6 mA to 15 mA Operating Current
- 0.8Ω Dynamic Impedance at Any Current
- **Available With Temperature Coefficient of** 0.01%/°C
- 7µV Wideband Noise
- 5% Initial Tolerance
- 0.002% Long Term Stability
- Low Cost
- Subsurface Zener

Connection Diagram

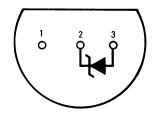


Figure 1. Bottom View Plastic Package (TO-92) See Package LP

DESCRIPTION

The LM329 is a precision multi-current temperaturecompensated 6.9V zener reference with dynamic impedance a factor of 10 to 100 less than discrete diodes. Constructed in a single silicon chip, the LM329 uses active circuitry to buffer the internal zener allowing the device to operate over a 0.5 mA to 15 mA range with virtually no change in performance. The LM329 is available with a temperature coefficients of 0.01%/°C. This reference also has excellent long term stability and low noise.

A new subsurface breakdown zener used in the LM329 gives lower noise and better long-term stability than conventional IC zeners. Further the zener and temperature compensating transistor are made by a planar process so they are immune to problems that plague ordinary zeners. For example, there is virtually no voltage shift in zener voltage due to temperature cycling and the device is insensitive to stress on the leads.

The LM329 can be used in place of conventional zeners with improved performance. The low dynamic impedance simplifies biasing and the wide operating current allows the replacement of many zener types.

The LM329 for operation over 0°C to 70°C is available in a TO-92 epoxy package.

Typical Application

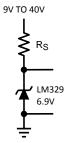


Figure 2. Simple Reference



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾

Reverse Breakdown Current	30 mA	
Forward Current	2 mA	
Operating Temperature Range	LM329	0°C to +70°C
Storage Temperature Range	−55°C to +150°C	
Soldering Information	TO-92 package: 10 sec.	260°C

(1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.

Electrical Characteristics⁽¹⁾

Parameter	Conditions	Min	Тур	Max	Units
Reverse Breakdown Voltage	$T_A = 25^{\circ}C, 0.6 \text{ mA} \le I_R \le 15 \text{ mA}$	6.6	6.9	7.25	V
Reverse Breakdown Change $T_A = 25^{\circ}C$, with Current ⁽²⁾	0.6 mA ≤ I _R ≤ 15 mA		9	20	mV
Reverse Dynamic Impedance ⁽²⁾	$T_{A} = 25^{\circ}C, I_{R} = 1 \text{ mA}$		0.8	2	Ω
RMS Noise	$T_A = 25^{\circ}C$, 10 Hz $\leq F \leq$ 10 kHz		7	100	μV
Long Term Stability (1000 hours)	$T_A = 45^{\circ}C \pm 0.1^{\circ}C,$ $I_R = 1 \text{ mA} \pm 0.3\%$		20		ppm
Temperature Coefficient	I _R = 1 mA		50	100	ppm/°C
Change In Reverse Breakdown Temperature Coefficient	1 mA ≤ I _R ≤ 15 mA		1		ppm/°C
Reverse Breakdown Change with Current	1 mA ≤ I _R ≤ 15 mA		12		mV
Reverse Dynamic Impedance	1 mA ≤ I _R ≤ 15 mA		1		Ω

(1) These specifications apply for 0°C ≤ T_A ≤ +70°C for the LM329 unless otherwise specified. The maximum junction temperature for a LM329 is 100°C. For operating at elevated temperature. The TO-92 package, the derating is based on 180°C/W junction to ambient with 0.4″ leads from a PC board and 160°C/W junction to ambient with 0.125″ lead length to a PC board.

(2) These changes are tested on a pulsed basis with a low duty-cycle. For changes versus temperature, compute in terms of tempco.

Typical Applications

Figure 3. Low Cost 0–25V Regulator

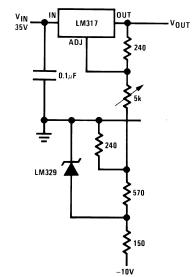
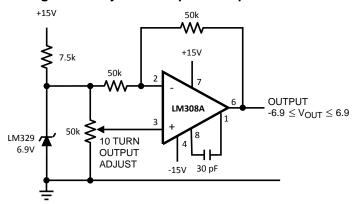




Figure 4. Adjustable Bipolar Output Reference



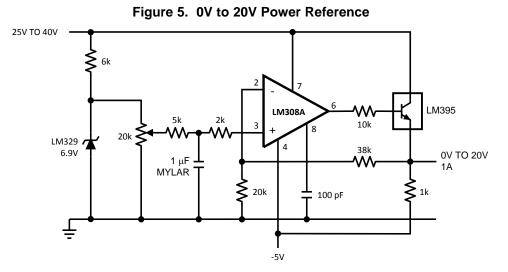
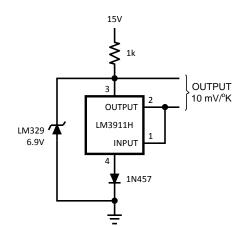


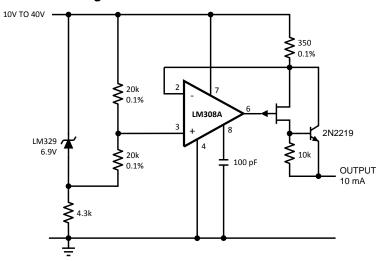
Figure 6. External Reference for Temperature Transducer



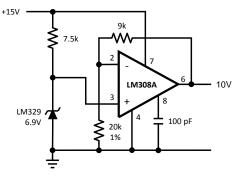


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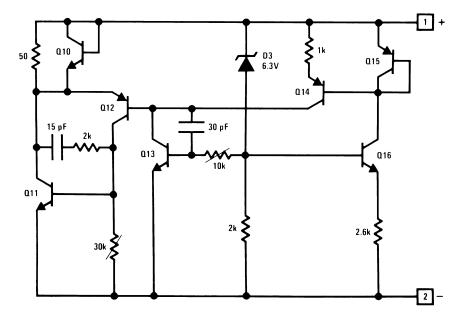
Figure 7. Positive Current Source







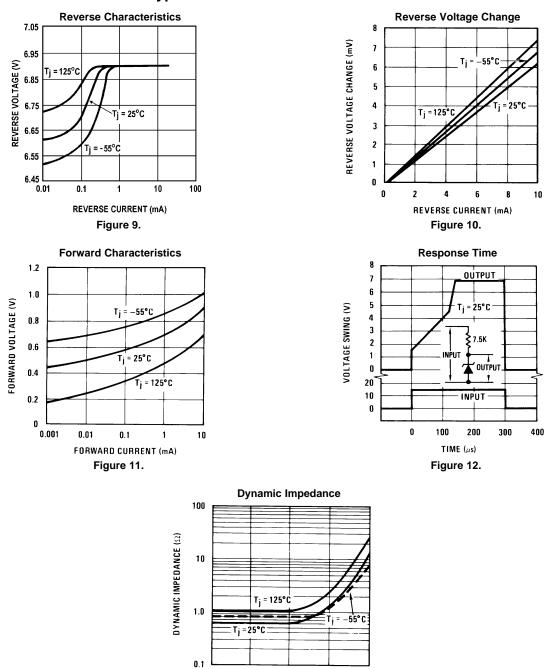
Schematic Diagram







Typical Performance Characteristics



FREQUENCY (Hz) Figure 13.

1k

10k

100k

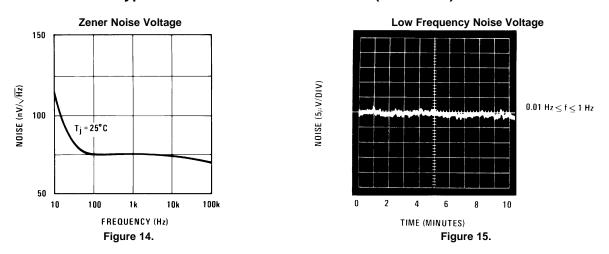
10

100



SNVS748F-MAY 2000-REVISED APRIL 2013

Typical Performance Characteristics (continued)



Page

Changes from Revision E (April 2013) to Revision F

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REVISION HISTORY

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25-Aug-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LM329DZ/NOPB	NRND	TO-92	LP	3	1800	Green (RoHS & no Sb/Br)	CU SN	N / A for Pkg Type	0 to 70	LM329 DZ	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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GENERIC PACKAGE VIEW

TO-92 - 5.34 mm max height TRANSISTOR OUTLINE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



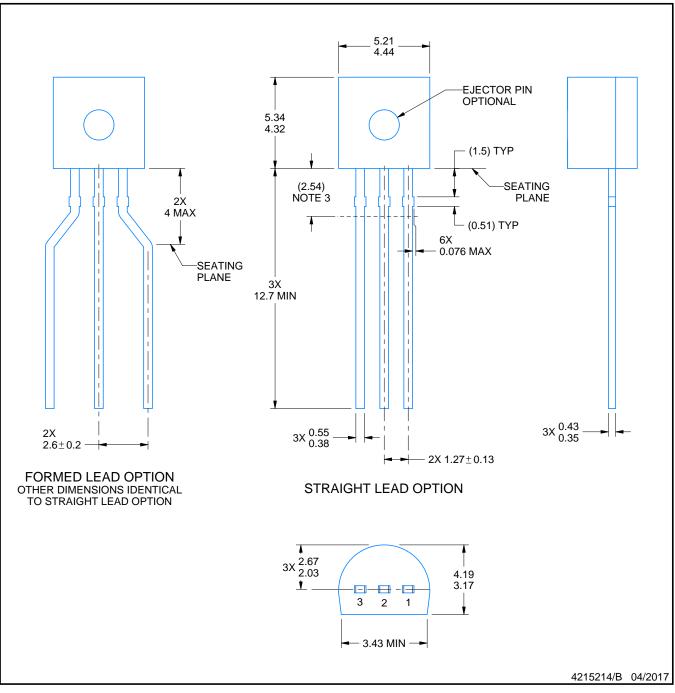
LP0003A



PACKAGE OUTLINE

TO-92 - 5.34 mm max height

TO-92



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
 Reference JEDEC TO-226, variation AA.
- 5. Shipping method:

 - a. Straight lead option available in bulk pack only.b. Formed lead option available in tape and reel or ammo pack.
 - c. Specific products can be offered in limited combinations of shipping medium and lead options.
 - d. Consult product folder for more information on available options.

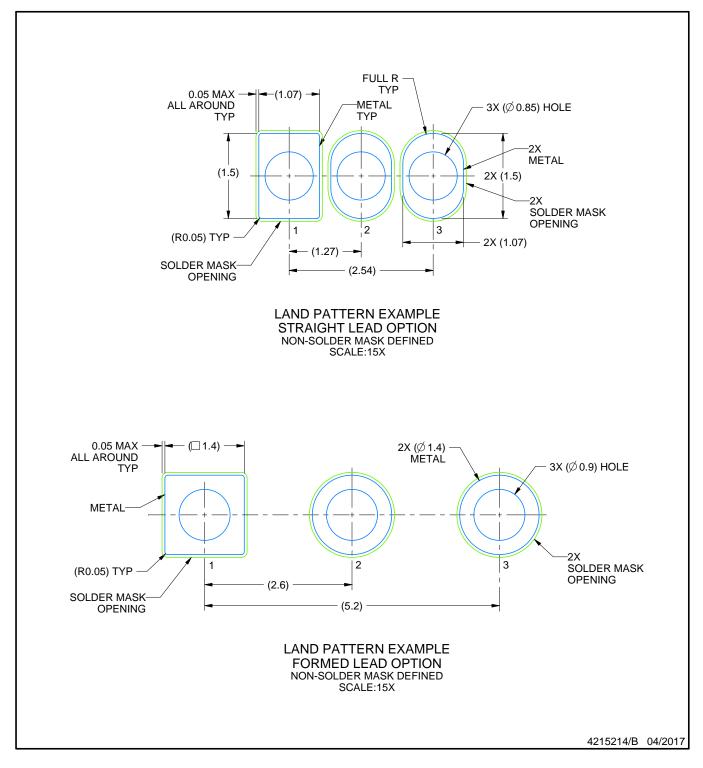


LP0003A

EXAMPLE BOARD LAYOUT

TO-92 - 5.34 mm max height

TO-92





LP0003A

TAPE SPECIFICATIONS

TO-92 - 5.34 mm max height

TO-92

